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April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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H5N2001LD, H5N2001LS, H5N2001LM

Silicon N Channel MOS FET High Speed Power Switching

REJ03G1339-0600 Rev.6.00 Jul 14, 2006

Features

- Low on-resistance
- Low leakage current
- High speed switching

Outline

RENESAS Package code: PRSS0004AE-A (Package name: LDPAK (L))



H5N2001LD

RENESAS Package code: PRSS0004AE-C (Package name: LDPAK (S)-(2))



H5N2001LM

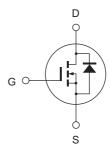
RENESAS Package code: PRSS0004AE-B (Package name: LDPAK (S)-(1))



1. Gate

- 2. Drain 3. Source
- 4. Drain

H5N2001LS



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	200	V
Gate to source voltage	V_{GSS}	±30	V
Drain current	I _D	20	А
Drain peak current	I _D (pulse) Note 1	80	А
Body to drain diode reverse drain current	I _{DR}	20	А
Body to drain diode reverse drain peak current	I _{DR (pulse)} Note 1	80	А
Avalanche current	I _{AP} Note 3	20	А
Channel dissipation	Pch Note 2	75	W
Channel to case Thermal Impedance	θ ch-c	1.67	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

3. Tch ≤ 150°C

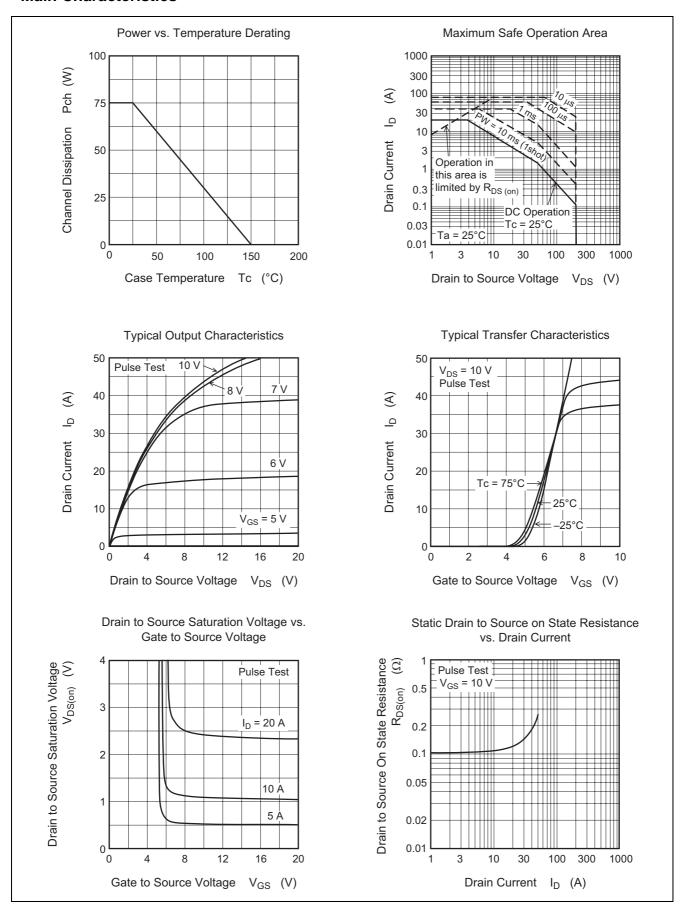
Electrical Characteristics

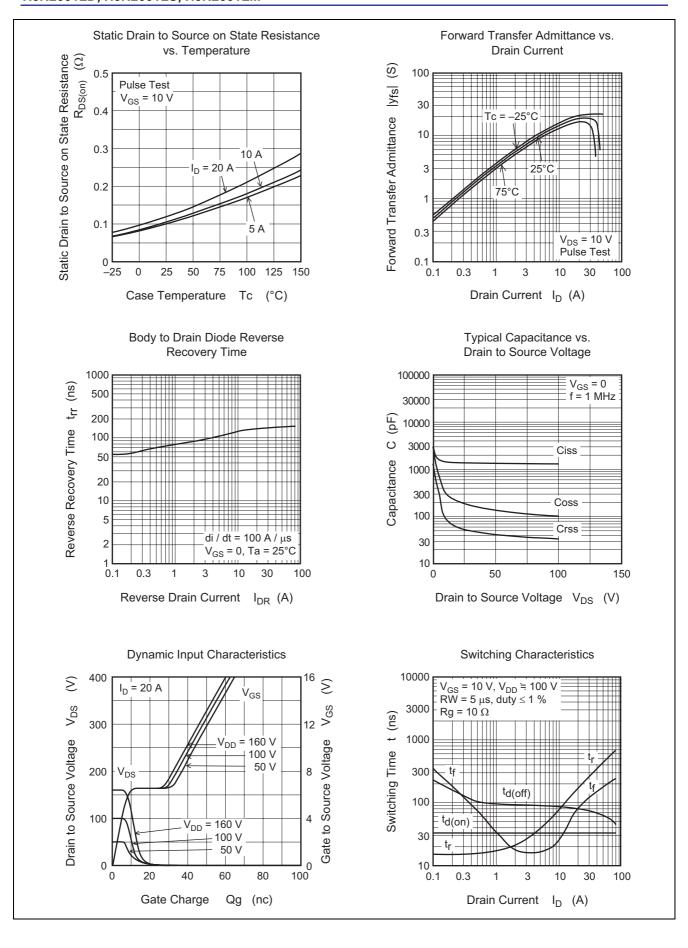
 $(Ta = 25^{\circ}C)$

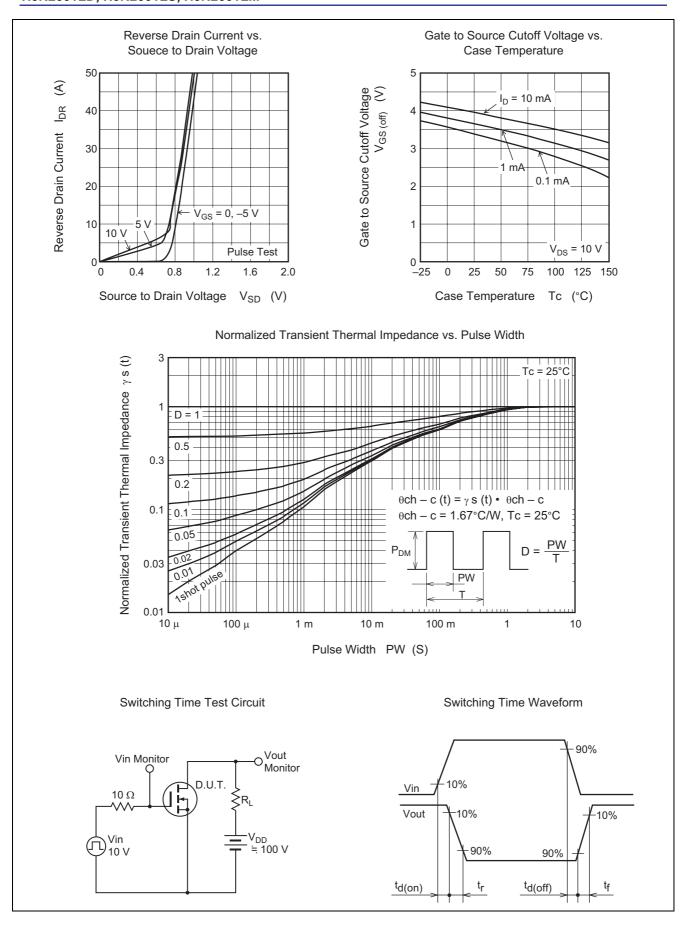
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR) DSS}	200	_		V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I _{GSS}		_	±0.1	μΑ	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}		_	1	μΑ	$V_{DS} = 200 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS (off)}	3.0	_	4.5	>	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on state resistance	R _{DS (on)}	_	0.100	0.125	Ω	$I_D = 10 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note 4}}$
Forward transfer admittance	y _{fs}	8	14		Ø	$I_D = 10 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note 4}}$
Input capacitance	Ciss	_	1350	_	pF	V _{DS} = 25 V
Output capacitance	Coss	_	180	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	55	_	pF	f = 1 MHz
Turn-on delay time	t _{d (on)}	_	35	_	ns	I _D = 10 A
Rise time	t _r	_	70	_	ns	$R_L = 10 \Omega$
Turn-off delay time	t _{d (off)}	_	85	_	ns	V _{GS} = 10 V
Fall time	t _f	_	20	_	ns	$Rg = 10 \Omega$
Total gate charge	Qg	_	44	_	nC	V _{DD} = 160 V
Gate to source charge	Qgs	_	8	_	nC	V _{GS} = 10 V
Gate to drain charge	Qgd	_	22	_	nC	I _D = 20 A
Body to drain diode forward voltage	V_{DF}	_	0.9	1.4	V	$I_F = 20 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body to drain diode reverse recovery time	t _{rr}	_	140	_	ns	I _F = 20 A, V _{GS} = 0
Body to drain diode reverse recovery	Qrr	_	0.7	_	μС	di _F /dt = 100 A/μs
charge						

Note: 4. Pulse test

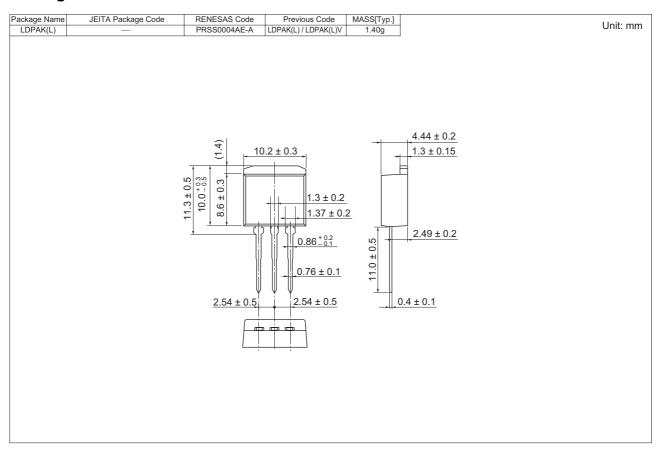
Main Characteristics

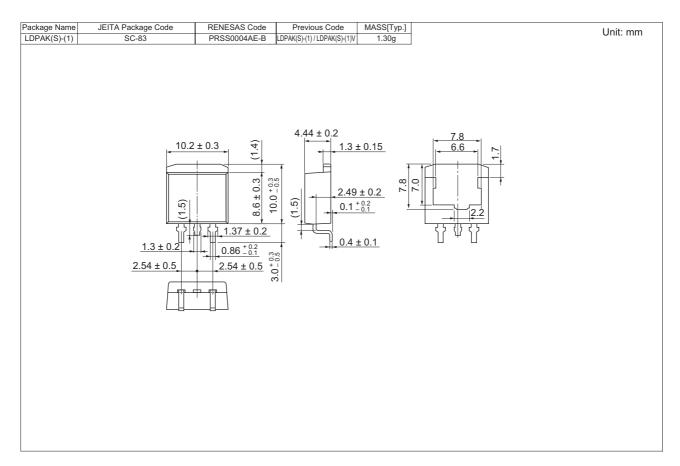


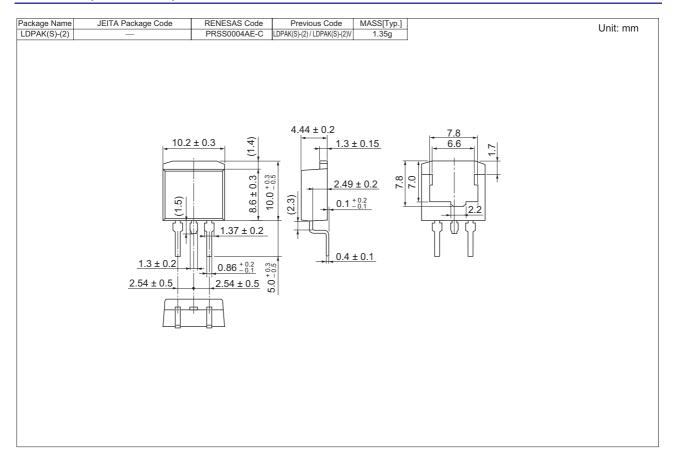




Package Dimensions







Ordering Information

Part Name	Quantity	Shipping Container
H5N2001LD-E	500 pcs	Box (Conductive Sack)
H5N2001LSTL-E	1000 pcs	Taping
H5N2001LMTL-E	1000 pcs	Taping

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